

**Radiation Hardened Quad 2-Input OR Gate**

The Radiation Hardened ACS32MS is a Quad 2-Input OR Gate. For each gate, a HIGH level on either A or B input results in a HIGH level on the Y output. A LOW level on both the A and B inputs results in a LOW level on the Y output. All inputs are buffered and the outputs are designed for balanced propagation delay and transition times.

The ACS32MS is fabricated on a CMOS Silicon on Sapphire (SOS) process, which provides an immunity to Single Event Latch-up and the capability of highly reliable performance in any radiation environment. These devices offer significant power reduction and faster performance when compared to ALSTTL types.

**Specifications for Rad Hard QML devices are controlled by the Defense Supply Center in Columbus (DSCC). The SMD numbers listed below must be used when ordering.**

**Detailed Electrical Specifications for the ACS32MS are contained in SMD 5962-98624. A “hot-link” is provided on our homepage with instructions for downloading. [www.intersil.com/data/sm/index.asp](http://www.intersil.com/data/sm/index.asp)**

**Features**

- QML Qualified Per MIL-PRF-38535 Requirements
- 1.25 Micron Radiation Hardened SOS CMOS
- Radiation Environment
  - Latch-Up Free Under any Conditions
  - Total Dose . . . . .  $3 \times 10^5$  RAD (Si)
  - SEU Immunity . . . . .  $<1 \times 10^{-10}$  Errors/Bit/Day
  - SEU LET Threshold . . . . .  $>100\text{MeV}/(\text{mg}/\text{cm}^2)$
- Input Logic Levels . . . .  $V_{IL} = (0.3)(V_{CC})$ ,  $V_{IH} = (0.7)(V_{CC})$
- Output Current . . . . .  $\pm 8\text{mA}$  (Min)
- Quiescent Supply Current . . . . .  $100\mu\text{A}$  (Max)
- Propagation Delay . . . . . 12ns (Max)

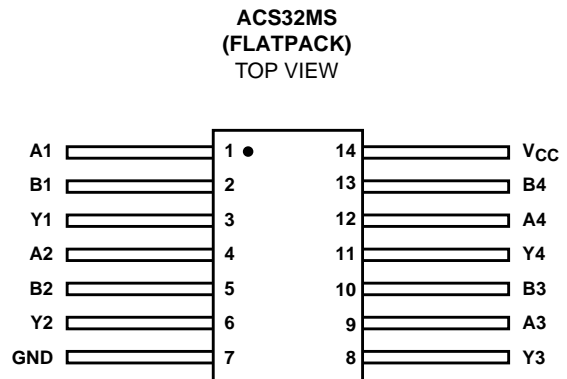
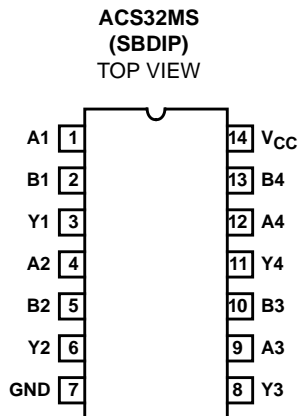
**Applications**

- High Speed Control Circuits
- Sensor Monitoring
- Low Power Designs

**Ordering Information**

| ORDERING NUMBER  | INTERNAL MKT. NUMBER | TEMP. RANGE (°C) | PACKAGE        | DESIGNATOR |
|------------------|----------------------|------------------|----------------|------------|
| 5962F9862401VCC  | ACS32DMSR-03         | -55 to 125       | 14 Ld SBDIP    | CDIP2-T14  |
| ACS32D/SAMPLE-03 | ACS32D/SAMPLE-03     | 25               | 14 Ld SBDIP    | CDIP2-T14  |
| 5962F9862401VXC  | ACS32KMSR-03         | -55 to 125       | 14 Ld Flatpack | CDFP4-F14  |
| ACS32K/SAMPLE-03 | ACS32K/SAMPLE-03     | 25               | 14 Ld Flatpack | CDFP4-F14  |
| 5962F9862401V9A  | ACS32HMSR-03         | 25               | Die            | N/A        |

**Pinouts**



**Die Characteristics**

**DIE DIMENSIONS:**

Size: 2390µm x 2390µm (94 mils x 94 mils)  
 Thickness: 525µm ± 25µm (20.6 mils ± 1 mil)  
 Bond Pad: 110µm x 110µm (4.3 x 4.3 mils)

**METALLIZATION: AL**

Metal 1 Thickness: 0.7µm ± 0.1µm  
 Metal 2 Thickness: 1.0µm ± 0.1µm

**SUBSTRATE POTENTIAL:**

Unbiased Insulator

**PASSIVATION**

Type: Phosphorous Silicon Glass (PSG)  
 Thickness: 1.30µm ± 0.15µm

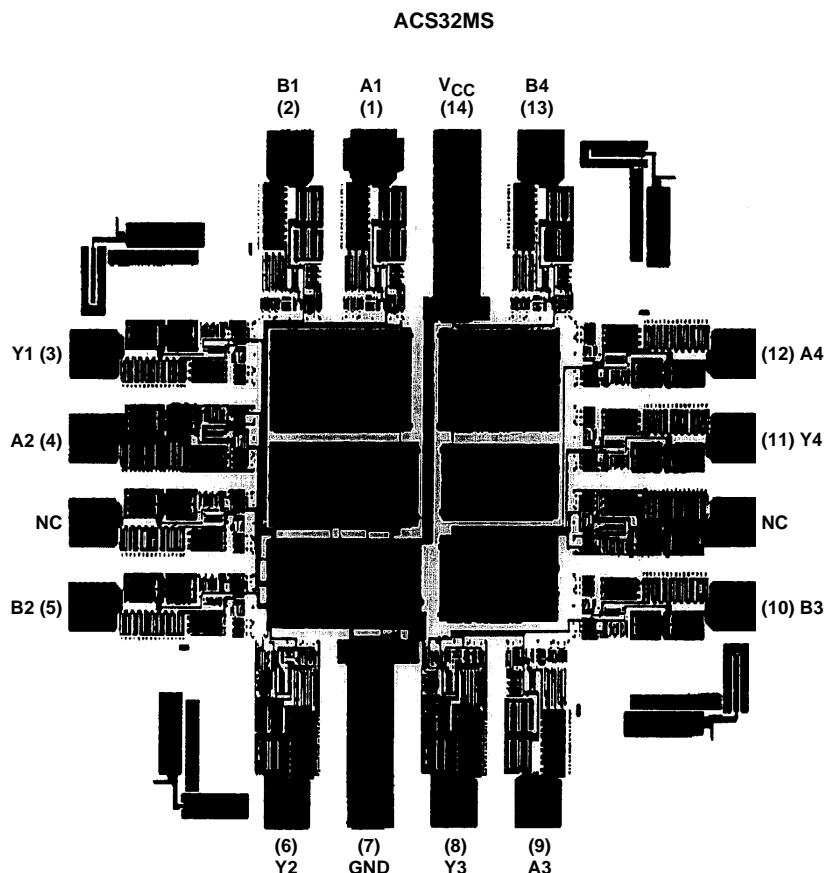
**SPECIAL INSTRUCTIONS:**

Bond V<sub>CC</sub> First

**ADDITIONAL INFORMATION:**

Worst Case Current Density: <math><2.0 \times 10^5 \text{ A/cm}^2</math>  
 Transistor Count: 116

**Metallization Mask Layout**



All Intersil semiconductor products are manufactured, assembled and tested under **ISO9000** quality systems certification.

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**Sales Office Headquarters**

**NORTH AMERICA**

Intersil Corporation  
 P. O. Box 883, Mail Stop 53-204  
 Melbourne, FL 32902  
 TEL: (321) 724-7000  
 FAX: (321) 724-7240

**EUROPE**

Intersil SA  
 Mercure Center  
 100, Rue de la Fusee  
 1130 Brussels, Belgium  
 TEL: (32) 2.724.2111  
 FAX: (32) 2.724.22.05

**ASIA**

Intersil (Taiwan) Ltd.  
 7F-6, No. 101 Fu Hsing North Road  
 Taipei, Taiwan  
 Republic of China  
 TEL: (886) 2 2716 9310  
 FAX: (886) 2 2715 3029